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CONFIRMATION NO. 5541

SERIAL NUMBER 10/701,165	FILING DATE 11/04/2003 RULE	CLASS 257	GROUP ART UNIT 2811	ATTORNEY DOCKET NO. 02GR109854488	
<b>APPLICANTS</b>  Pierre Morin, Grenoble, FRANCE;  Jorge Luis Regolini, Bernin, FRANCE;  <i>None</i>					
** CONTINUING DATA *****  <i>Yes</i>					
** FOREIGN APPLICATIONS ***** FRANCE 0213837 11/05/2002					
IF REQUIRED, FOREIGN FILING LICENSE GRANTED ** 02/13/2004					
Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no 35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance Verified and Acknowledged <i>[Signature]</i> Examiner's Signature <i>[Initials]</i>		STATE OR COUNTRY FRANCE	SHEETS DRAWING 3	TOTAL CLAIMS 27	INDEPENDENT CLAIMS 4
<b>ADDRESS</b> 27975 ALLEN, DYER, DOPPELT, MILBRATH & GILCHRIST P.A. 1401 CITRUS CENTER 255 SOUTH ORANGE AVENUE P.O. BOX 3791 ORLANDO , FL 32802-3791					
<b>TITLE</b> Semiconductor device with MOS transistors with an etch-stop layer having an improved residual stress level and method for fabricating such a semiconductor device					
FILING FEE	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT		<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees ( Filing ) <input type="checkbox"/> 1.17 Fees ( Processing Ext. of time )		